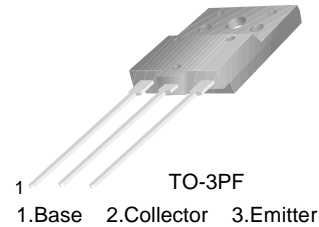


TIP140F/141F/142F

Monolithic Construction With Built In Base-Emitter Shunt Resistors

- Complement to TIP145F/146F/147F
- High DC Current Gain : $h_{FE} = 1000$ @ $V_{CE} = 4V$, $I_C = 5A$ (Min.)
- Industrial Use

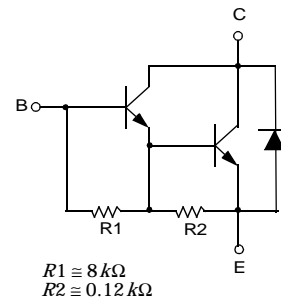


NPN Epitaxial Darlington Transistor

Absolute Maximum Ratings $T_C=25^\circ\text{C}$ unless otherwise noted

| Symbol | Parameter | Value | Units |
|-----------|--|------------|------------------|
| V_{CBO} | Collector-Base Voltage : TIP140F | 60 | V |
| | : TIP141F | 80 | V |
| | : TIP142F | 100 | V |
| V_{CEO} | Collector-Emitter Voltage : TIP140F | 60 | V |
| | : TIP141F | 80 | V |
| | : TIP142F | 100 | V |
| V_{EBO} | Emitter-Base Voltage | 5 | V |
| I_C | Collector Current (DC) | 10 | A |
| I_{CP} | Collector Current (Pulse) | 15 | A |
| I_B | Base Current (DC) | 0.5 | A |
| P_C | Collector Dissipation ($T_C=25^\circ\text{C}$) | 60 | W |
| T_J | Junction Temperature | 150 | $^\circ\text{C}$ |
| T_{STG} | Storage Temperature | - 65 ~ 150 | $^\circ\text{C}$ |

Equivalent Circuit



Electrical Characteristics $T_C=25^\circ\text{C}$ unless otherwise noted

| Symbol | Parameter | Test Condition | Min. | Typ. | Max. | Units | |
|----------------|--------------------------------------|--|-----------------|------|-------------|-----------------------------------|---------------|
| $V_{CEO(sus)}$ | Collector-Emitter Sustaining Voltage | $I_C = 30\text{mA}$, $I_B = 0$ | 60 80 100 | | | V | |
| | : TIP140F | | | | | V | |
| | : TIP141F | | | | | V | |
| | : TIP142F | | | | | V | |
| I_{CEO} | Collector Cut-off Current | $V_{CE} = 30V$, $I_B = 0$ $V_{CE} = 40V$, $I_B = 0$ $V_{CE} = 50V$, $I_B = 0$ | | | 2 2 2 | mA mA mA | |
| | : TIP140F | | | | | mA | |
| | : TIP141F | | | | | mA | |
| | : TIP142F | | | | | mA | |
| I_{CBO} | Collector Cut-off Current | $V_{CB} = 60V$, $I_E = 0$ $V_{CB} = 80V$, $I_E = 0$ $V_{CB} = 100V$, $I_E = 0$ | | | 1 1 1 | mA mA mA | |
| | : TIP140F | | | | | mA | |
| | : TIP141F | | | | | mA | |
| | : TIP142F | | | | | mA | |
| I_{EBO} | Emitter Cut-off Current | $V_{BE} = 5V$, $I_C = 0$ | | | 2 | mA | |
| h_{FE} | DC Current Gain | $V_{CE} = 4V$, $I_C = 5A$ $V_{CE} = 4V$, $I_C = 10A$ | 1000 500 | | | | |
| $V_{CE(sat)}$ | Collector-Emitter Saturation Voltage | $I_C = 5A$, $I_B = 10\text{mA}$ $I_C = 10A$, $I_B = 40\text{mA}$ | | | 2 3 | V V | |
| | | | | | | $I_C = 10A$, $I_B = 40\text{mA}$ | 3.5 |
| $V_{BE(on)}$ | Base-Emitter On Voltage | $V_{CE} = 4V$, $I_C = 10A$ | | | 3 | V | |
| t_D | Delay Time | $V_{CC} = 30V$, $I_C = 5A$ $I_B 1 = 20\text{mA}$, $I_B 2 = -20\text{mA}$ $R_L = 6\Omega$ | | 0.15 | | μs | |
| t_R | Rise Time | | | | | 0.55 | μs |
| t_{STG} | Storage Time | | | | | 2.5 | μs |
| t_F | Fall Time | | | | | 2.5 | μs |

Typical Characteristics

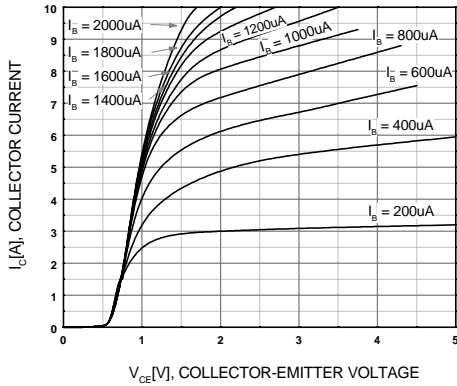


Figure 1. Static Characteristics

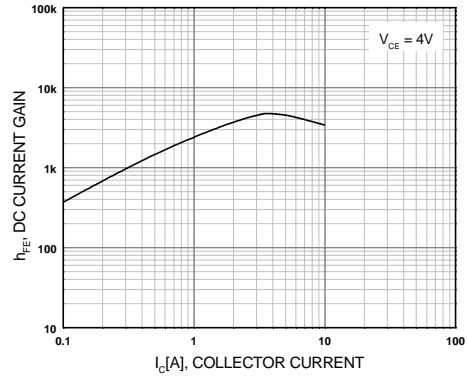


Figure 2. DC current Gain

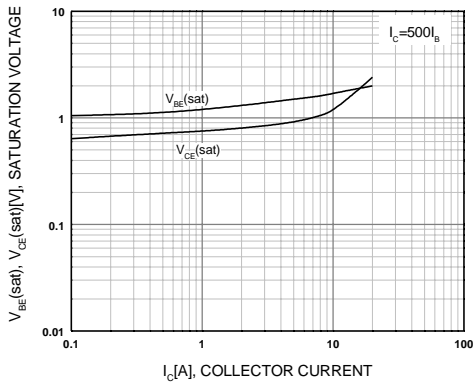


Figure 3. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

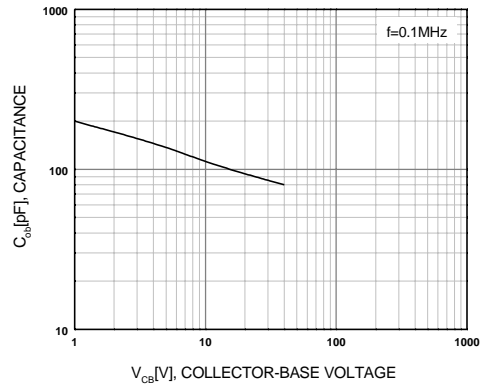


Figure 4. Collector Output Capacitance

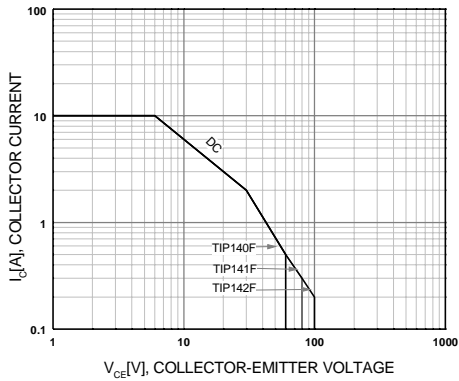


Figure 5. Safe Operating Area

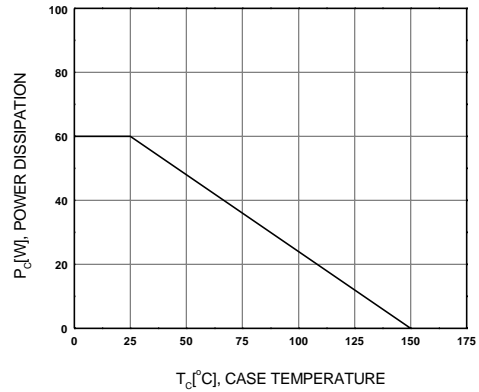
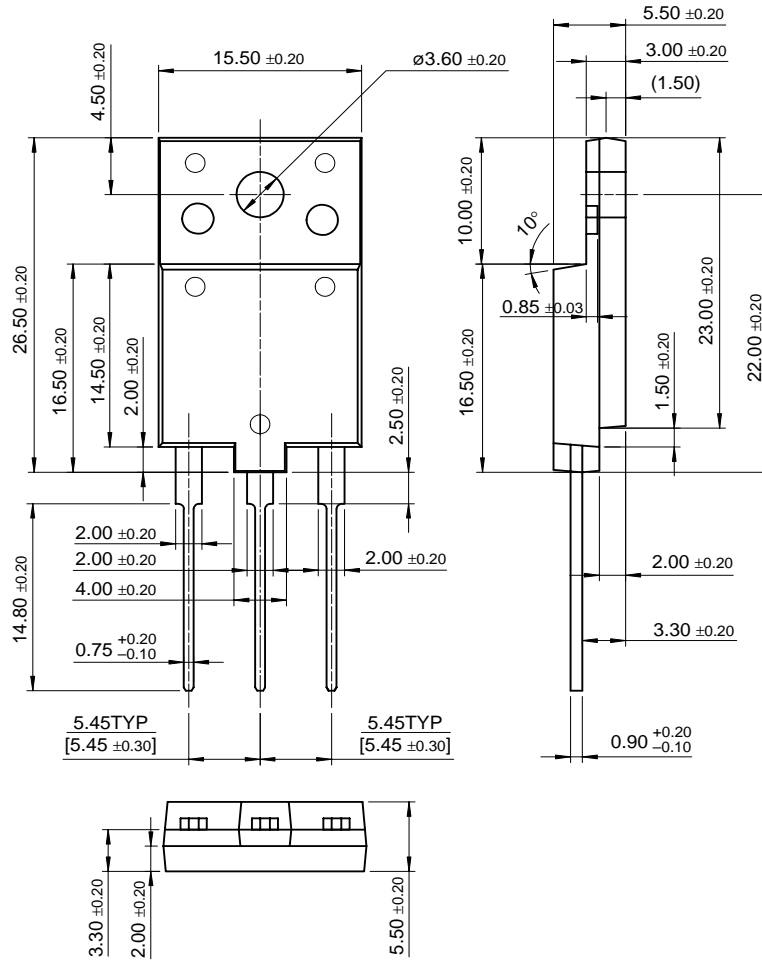


Figure 6. Power Derating

Package Dimensions

TO-3PF

TIP140F/141F/142F



Dimensions in Millimeters

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